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Quantum Sensing and Nanophotonic Devices V

**Rengarajan Sudharsanan
Christopher Jelen**
Editors

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Contents

vii	Conference Committee
ix	Introduction

SESSION 1 QUANTUM SOURCES I

- 6900 03 **Robust single-mode emission from mid-IR photonic crystal interband cascade lasers (Invited Paper)** [6900-02]
C. S. Kim, M. Kim, C. L. Canedy, W. W. Bewley, D. C. Larrabee, J. A. Nolde, J. R. Lindle, I. Vurgaftman, J. R. Meyer, Naval Research Lab. (USA)
- 6900 04 **Interband GaSb-based laser diodes for spectral regions of 2.3–2.4 μm and 3–3.1 μm with improved room-temperature performance (Invited Paper)** [6900-03]
G. Belenky, D. Donetski, L. Shterengas, T. Hosoda, J. Chen, G. Kipshidze, M. Kisin, Stony Brook Univ. (USA); D. Westerfeld, Power Photonic Corp. (USA)
- 6900 05 **Type-II superlattices and quantum cascade lasers for MWIR and LWIR free-space communications** [6900-04]
A. Hood, A. Evans, M. Razeghi, Northwestern Univ. (USA)

SESSION 2 QUANTUM SOURCES II

- 6900 08 **Recent advances in long wavelength quantum dot based lasers (Invited Paper)** [6900-07]
A. Ramdane, A. Martinez, CNRS, Lab. de Photonique et de Nanostructures (France); S. Azouigui, CNRS, Lab. de Photonique et de Nanostructures (France) and Institut National des Télécommunications, CNRS SAMOVAR (France); D.-Y. Cong, K. Merghem, A. Akrouf, C. Gosset, G. Moreau, CNRS, Lab. de Photonique et de Nanostructures (France); F. Lelarge, B. Dagens, J.-G. Provost, A. Accard, O. Le Gouezigou, Alcatel-Thales 3-5 Lab. (France); I. Krestnikov, A. Kovsh, Innolume GmbH (Germany); M. Fischer, Nanoplus GmbH (Germany)
- 6900 09 **Controlled emission of polarized infrared light by a nanocavity equipped optical source** [6900-08]
K. Ikeda, Nalux Co., Ltd. (Japan); H. T. Miyazaki, T. Kasaya, National Institute for Materials Science (Japan); K. Yamamoto, Y. Inoue, K. Fujimura, T. Kanakugi, M. Okada, K. Hatade, Nalux Co., Ltd. (Japan)
- 6900 0A **Electrically pumped photonic crystal distributed feedback quantum cascade lasers (Best Student Paper Award)** [6900-09]
Y. Bai, P. Sung, S. R. Darvish, W. Zhang, A. Evans, S. Slivken, M. Razeghi, Northwestern Univ. (USA)

SESSION 3 QUANTUM SOURCES III

- 6900 0B **Overview of quantum cascade laser research at the Center for Quantum Devices (Invited Paper)** [6900-10]
S. Slivken, A. Evans, J. Nguyen, Y. Bai, P. Sung, S. R. Darvish, W. Zhang, M. Razeghi, Northwestern Univ. (USA)
- 6900 0C **Toward regulated photon generations from semiconductor quantum dots and their applications (Invited Paper)** [6900-11]
I. Suemune, H. Kumano, Hokkaido Univ. (Japan) and Japan Science and Technology, CREST (Japan); Y. Hayashi, Hokkaido Univ. (Japan) and Japan Society for the Promotion of Science (Japan); K. Tanaka, Japan Science and Technology, CREST (Japan) and Hamamatsu Photonics K. K. (Japan); T. Akazaki, Japan Science and Technology, CREST (Japan) and NTT Basic Research Labs. (Japan); M. Jo, Hokkaido Univ. (Japan) and Japan Society for the Promotion of Science (Japan); Y. Idutsu, Hokkaido Univ. (Japan) and Japan Science and Technology, CREST (Japan)
- 6900 0E **Mid-infrared vertical-cavity surface-emitting lasers based on lead salt/BaF₂ Bragg mirrors** [6900-52]
M. Eibelhuber, T. Schwarzl, Johannes Kepler Univ. (Austria); A. Winter, H. Pascher, Univ. Bayreuth (Germany); W. Heiss, G. Springholz, Johannes Kepler Univ. (Austria)

SESSION 4 SUPERLATTICES AND QUANTUM DETECTORS I

- 6900 0F **Type II strained layer superlattice: a potential infrared sensor material for space (Keynote Paper)** [6900-13]
L. Zheng, Institute for Defense Analyses (USA); M. Z. Tidrow, A. Novello, Missile Defense Agency (USA); H. Weichel, Computer Sciences Corp. (USA); S. Vohra, SPARTA Corp. (USA)
- 6900 0H **Novel routes in heteroepitaxy and selective area growth for nanophotonics (Invited Paper)** [6900-15]
S. Lourdudoss, F. Olsson, KTH (Sweden); Y. Sun, Svedice AB (Sweden)

SESSION 5 SUPERLATTICES AND QUANTUM DETECTORS II

- 6900 0I **Type II InSb/InAs quantum dot structures grown by molecular beam epitaxy using Sb₂ and As₂ fluxes (Invited Paper)** [6900-16]
P. J. Carrington, Lancaster Univ. (United Kingdom); V. A. Solov'ev, Lancaster Univ. (United Kingdom) and Ioffe Physico-Technical Institute (Russia); Q. Zhuang, Lancaster Univ. (United Kingdom); S. V. Ivanov, Ioffe Physico-Technical Institute (Russia); A. Krier, Lancaster Univ. (United Kingdom)
- 6900 0J **Advantages of quantum cascade detectors (Invited Paper)** [6900-17]
A. Gomez, Alcatel Thales 3-5 Lab. (France) and Lab. MPQ, Univ. Paris 7, CNRS (France); M. Carras, A. Nedelcu, E. Costard, X. Marcadet, Alcatel Thales 3-5 Lab. (France); V. Berger, Alcatel Thales 3-5 Lab. (France) and Lab. MPQ, Univ. Paris 7, CNRS (France)
- 6900 0L **Proposal for (110) InAs/GaSb superlattices for infrared detection** [6900-19]
F. Szmulowicz, Univ. of Dayton Research Institute (USA); H. J. Haugan, Universal Technology Corp. (USA); G. J. Brown, Air Force Research Lab. (USA)

SESSION 6 SUPERLATTICES AND QUANTUM DETECTORS III

- 6900 0M **High-performance focal plane array based on type-II InAs/GaSb superlattice heterostructures (Invited Paper)** [6900-20]
P.-Y. Delaunay, M. Razeghi, Northwestern Univ. (USA)
- 6900 0N **III-nitride photon counting avalanche photodiodes (Invited Paper)** [6900-21]
R. McClintock, J. L. Pau, K. Minder, C. Bayram, M. Razeghi, Northwestern Univ. (USA)
- 6900 0O **Broadband photoresponse from InAs quantum dots embedded in a graded well for visible to mid-infrared detection** [6900-22]
B. S. Passmore, J. Wu, E. A. DeCuir, Jr., O. Manasreh, Univ. of Arkansas (USA); P. M. Lytvyn, V. Lashkaryov Institute of Semiconductor Physics (USA); E. Marega, Jr., V. P. Kunets, G. J. Salamo, Univ. of Arkansas (USA)
- 6900 0P **Interface roughness estimate from carrier transport in InAs/GaSb superlattices** [6900-23]
F. Szmulowicz, Univ. of Dayton Research Institute (USA); S. Elhamri, Univ. of Dayton (USA); H. J. Haugan, Universal Technology Corp. (USA); G. J. Brown, W. C. Mitchel, Air Force Research Lab. (USA)

SESSION 7 SUPERLATTICES AND QUANTUM DETECTORS IV

- 6900 0S **Progress in MOVPE-growth of InGaN and InN (Invited Paper)** [6900-26]
T. Matsuoka, Tohoku Univ., CREST (Japan)

SESSION 8 NOVEL SENSORS I

- 6900 0W **Design approaches for digitally dominated active pixel sensors: leveraging Moore's Law scaling in focal plane readout design (Invited Paper)** [6900-30]
B. Tyrrell, R. Berger, C. Colanero, J. Costa, M. Kelly, E. Ringdahl, K. Schultz, J. Wey, MIT Lincoln Lab. (USA)

SESSION 9 NOVEL SENSORS II

- 6900 0Z **Recent advances and applications of mid-infrared based trace gas sensor technology (Invited Paper)** [6900-33]
F. K. Tittel, Y. Bakhirkin, A. Kosterev, R. Lewicki, S. So, G. Wysocki, R. F. Curl, Rice Univ. (USA)

SESSION 10 NOVEL SENSORS III

- 6900 12 **Design and modeling of nanophotonic beam structures as optical NEMS sensors** [6900-36]
C. Lee, National Univ. of Singapore (Singapore) and Institute of Microelectronics, A*STAR (Singapore); J. Thillaigovindan, National Univ. of Singapore (Singapore); A. Yu, Institute of Microelectronics, A*STAR (Singapore); R. Radhakrishnan, National Univ. of Singapore (Singapore); C.-C. Chen, National Central Univ. (Taiwan); Y.-T. Chao, Yuan Ze Univ. (Taiwan); J. H. Lau, Institute of Microelectronics, A*STAR (Singapore)

- 6900 14 **A quantum cascade laser based room temperature spectrometer for sensitive detection of ammonia and ethylene** [6900-53]
J. Manne, W. Jäger, J. Tulip, Univ. of Alberta (Canada)

SESSION 11 QUANTUM CRYPTOGRAPHY AND IMAGING

- 6900 17 **Sub-diffraction optical imaging by high-spatial-resolution photodetectors and Fourier signal processing** [6900-41]
M. Hashemi, M. Hegg, B. A. Parviz, L. Y. Lin, Univ. of Washington (USA)

SESSION 12 SINGLE PHOTON DETECTOR I

- 6900 19 **Multiplexed photon-counting detectors (Invited Paper)** [6900-43]
S. V. Polyakov, National Institute of Standards and Technology (USA); V. Schettini, I. P. Degiovanni, G. Brida, Istituto Nazionale di Ricerca Metrologica (Italy); A. Migdall, National Institute of Standards and Technology (USA)
- 6900 1B **High efficiency 1.55 μm Geiger-mode single photon counting avalanche photodiodes operating near 0°C** [6900-45]
P. Yuan, J. Boisvert, R. Sudharsanan, T. Isshiki, P. McDonald, Boeing Spectrolab, Inc. (USA); M. Salisbury, Boeing SVS, Inc. (USA); M. Liu, J. C. Campbell, Univ. of Virginia (USA)

SESSION 13 SINGLE PHOTON DETECTOR II

- 6900 1C **Time-of-flight sensing using time-correlated single-photon counting (Invited Paper)** [6900-46]
G. S. Buller, A. McCarthy, R. J. Collins, P. A. Hiskett, V. Fernandez, S. Hernandez-Marin, A. M. Wallace, Heriot-Watt Univ. (United Kingdom)
- 6900 1D **Large-area low-jitter silicon single photon avalanche diodes (Invited Paper)** [6900-47]
M. Ghioni, Politecnico di Milano, DEI (Italy) and MPD Micro-Photon-Devices (Italy); A. Gulinatti, I. Rech, Politecnico di Milano, DEI (Italy); P. Maccagnani, IMM-CNR sezione di Bologna (Italy); S. Cova, Politecnico di Milano, DEI (Italy) and MPD Micro-Photon-Devices (Italy)
- 6900 1E **Single photon avalanche photodiodes for near-infrared photon counting** [6900-48]
M. A. Itzler, X. Jiang, R. Ben-Michael, B. Nyman, K. Slomkowski, Princeton Lightwave, Inc. (USA)
- 6900 1F **A novel quenching circuit to reduce afterpulsing of single photon avalanche diodes** [6900-49]
M. Liu, C. Hu, J. C. Campbell, Univ. of Virginia (USA); Z. Pan, M. M. Tashima, JDS Uniphase Corp. (USA)

Author Index

Conference Committee

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(Mexico)

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Session Chairs

- 1 Quantum Sources I
Christopher Jelen, Northrop Grumman Corporation (USA)
- 2 Quantum Sources II
Christopher Jelen, Northrop Grumman Corporation (USA)
- 3 Quantum Sources III
Robert R. Rice, Northrop Grumman Space Technology (USA)
- 4 Superlattices and Quantum Detectors I
Manijeh Razeghi, Northwestern University (USA)

- 5 Superlattices and Quantum Detectors II
Gail J. Brown, Air Force Research Laboratory (USA)
- 6 Superlattices and Quantum Detectors III
Sarath D. Gunapala, Jet Propulsion Laboratory (USA)
- 7 Superlattices and Quantum Detectors IV
Marija Strojnik-Scholl, Centro de Investigaciones en Óptica, A.C.
(Mexico)
- 8 Novel Sensors I
Manijeh Razeghi, Northwestern University (USA)
- 9 Novel Sensors II
Gail J. Brown, Air Force Research Laboratory (USA)
- 10 Novel Sensors III
Rengarajan Sudharsanan, Spectrolab, Inc. (USA)
- 11 Quantum Cryptography and Imaging
Mark A. Itzler, Princeton Lightwave, Inc. (USA)
- 12 Single Photon Detector I
Mark A. Itzler, Princeton Lightwave, Inc. (USA)
- 13 Single Photon Detector II
Rengarajan Sudharsanan, Spectrolab, Inc. (USA)

Introduction

Welcome to the Proceedings of SPIE Quantum Sensing and Nanophotonics V, Vol. 6900.

This volume contains papers from a conference held at the San Jose Convention Center, San Jose, California, USA, as part of the SPIE OPTO2008 and Photonics West Symposium.

This year's quantum sensing and nanophotonics conference, the fifth in the series, had very good representation from a broad range of attendees including industry and academia, enthusiasts and professionals, suppliers and users, and students and teachers. The conference was held over a four-day period, 20–23 January 2008, and featured a broad range of topics, presentations, and events.

The first day of the conference began with three sessions on quantum sources. The 13 papers in these sessions discussed topics that included 1) mid-infrared and long-wavelength-infrared semiconductor lasers including cascade lasers, 2) quantum dot and nano-wire LEDs and lasers, and 3) nanocavity optical sources.

The second day of the conference focused on superlattices and quantum detectors. Fifteen papers were presented in four sessions. Various aspects of superlattices as a potential sensor material for the infrared were discussed, as well as cascade detectors, quantum dot detectors, and detectors based on nitride materials.

The third day of the conference included three sessions focusing on novel sensors including magnetic semiconductors, silicon microspheres, and nanophotonic beam structures. The fourth and last day of the conference included one session on quantum cryptography and imaging and two sessions on single photon counting.

Many individuals and companies contributed in various ways to make this a very successful meeting. The conference committee plays an important role in ensuring the correct technical direction of the meeting and of course, the members play an important role at the conference itself including chairing sessions. Sincere thanks go to Gail Brown, Sarath Gunapala, Mark Itzler, Manijeh Razeghi, Robert Rice, Marija Strojnik-Scholl, and Ferechteh Hosseini Teherani.

Particular thanks are also due to the staff at SPIE who are instrumental in helping organize the conference. But most importantly we must thank the conference authors and attendees who ultimately make this meeting the successful event that it is.

As a final note, the Quantum Sensing and Nanophotonics conference will be on again next year, 24–29 January 2009. Next year we will be back in San Jose, California, at the San Jose Convention Center Photonics West Opto2009 symposium.

Rengarajan Sudharsanan
Christopher Jelen